

## Quad SPST CMOS Analog Switch with Latches

### Features

- Accepts 150-ns Write Pulse Width
- 5-V On-Chip Regulator
- Built on PLUS-40 Process
- Latches Are Transparent with  $\overline{WR}$  Low
- Low On-Resistance:  $60\ \Omega$

### Benefits

- Compatible with Most  $\mu P$  Buses
- Allows Wide Power Supply Tolerance Without Affecting TTL Compatibility
- Reduced Power Consumption
- Allows Flexibility of Design

### Applications

- $\mu P$  Based Systems
- Automatic Test Equipment
- Communication Systems
- Data Acquisition Systems
- Medical Instrumentation
- Factory Automation

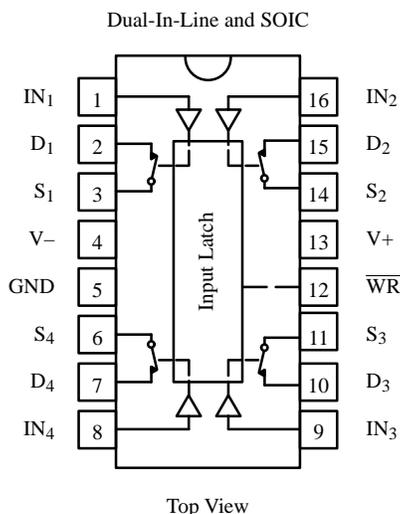
### Description

The DG221 is a monolithic quad single-pole, single-throw analog switch designed for precision switching applications in communication, instrumentation and process control systems. Featuring independent onboard latches and a common  $\overline{WR}$  pin, each DG221 can be memory mapped, and addressed as a single data byte for simultaneous switching.

Designed on the Siliconix PLUS-40 CMOS process, the DG221 combines low power and low on-resistance ( $60\ \Omega$  typical) while handling continuous currents up to 20 mA. An epitaxial layer prevents latchup.

The device features true bidirectional performance in the on condition. These switches guarantee a rail-to-rail blocking capability (44 V max), in the off condition.

### Functional Block Diagram and Pin Configuration



Four Latchable SPST Switches per Package

Truth Table

$IN_X$	$\overline{WR}$	Switch
0	0	ON
1	0	OFF
X		Control data latched-in, switches on or off as selected by last $IN_X$
X	1	Maintains previous state

Logic "0"  $\leq 0.8\ V$

Logic "1"  $\geq 2.4\ V$

Ordering Information

Temp Range	Package	Part Number
$0^\circ C$ to $70^\circ C$	16-Pin Plastic DIP	DG221CJ
$-40^\circ C$ to $85^\circ C$	16-Pin Narrow SOIC	DG221DY
$-55^\circ C$ to $125^\circ C$	16-Pin CerDIP	DG221AK/883

Updates to this data sheet may be obtained via facsimile by calling Siliconix FaxBack, 1-408-970-5600. Please request FaxBack document #70041.

# DG221

## Absolute Maximum Ratings

Voltages Referenced to V-		Power Dissipation (Package) <sup>b</sup>	
V+	44 V	16-Pin CerDIP <sup>c</sup>	900 mW
GND	25 V	16-Pin Plastic DIP <sup>d</sup>	470 mW
Digital Inputs <sup>a</sup> , V <sub>S</sub> , V <sub>D</sub>	(V-) -2 V to (V+) +2 V or 20 mA, whichever occurs first	16-Pin SOIC <sup>e</sup>	600 mW
Continuous Current (Any Terminal)	30 mA	Notes:	
Continuous Current, S or D	20 mA	a.	Signals on S <sub>X</sub> , D <sub>X</sub> , or IN <sub>X</sub> exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
Peak Current, S or D (Pulsed 1 ms, 10% duty cycle)	70 mA	b.	All leads welded or soldered to PC Board.
Storage Temperature:	(AK Suffix) -65 to 150°C	c.	Derate 12 mW/°C above 75°C
	(CJ and DY Suffix) -65 to 125°C	d.	Derate 6.5 mW/°C above 25°C
		e.	Derate 7.7 mW/°C above 75°C

## Schematic Diagram (Typical Channel)

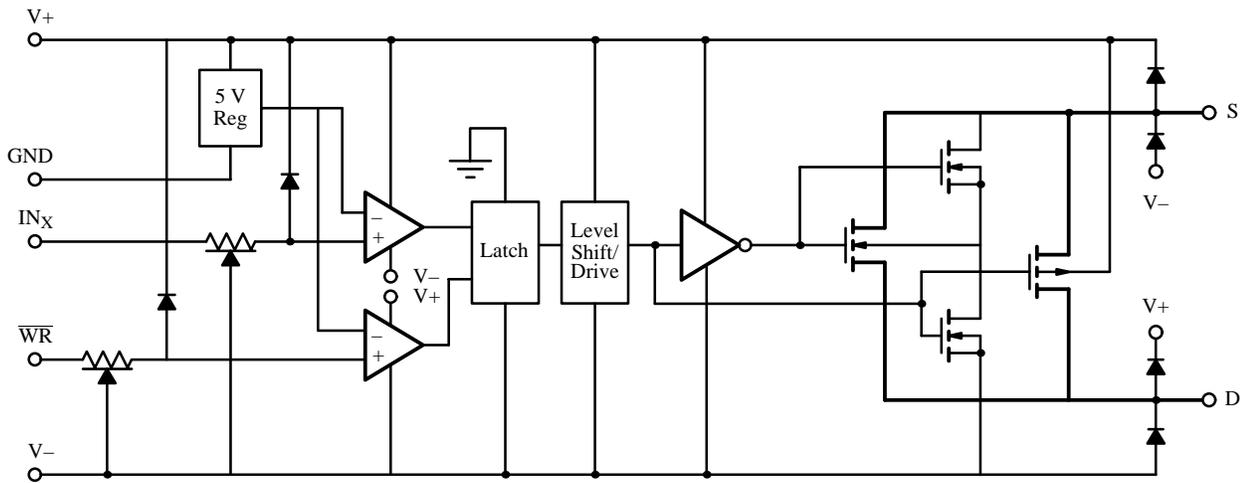


Figure 1.

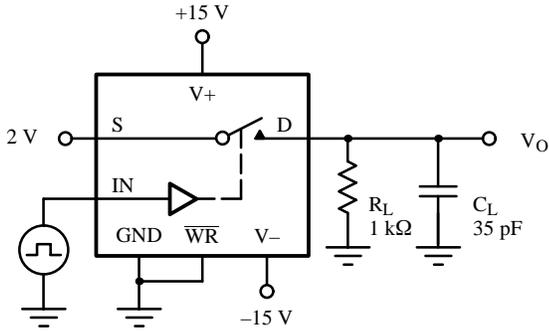
## Specifications<sup>a</sup>

Parameter	Symbol	Test Conditions Unless Otherwise Specified $V_+ = 15\text{ V}$ , $V_- = -15\text{ V}$ $V_{IN} = 2.4\text{ V}$ , $0.8^f\text{ V}$ , $\overline{WR} = 0$	Temp <sup>b</sup>	Typ <sup>c</sup>	A Suffix -55 to 125°C		D Suffix -40 to 85°C		Unit
					Min <sup>d</sup>	Max <sup>d</sup>	Min <sup>d</sup>	Max <sup>d</sup>	
<b>Analog Switch</b>									
Analog Signal Range <sup>e</sup>	$V_{ANALOG}$		Full		-15	15	-15	15	V
Drain-Source On-Resistance	$r_{DS(on)}$	$I_S = -10\text{ mA}$ , $V_D = \pm 10\text{ V}$	Room Full	60		90 135		90 135	$\Omega$
Source Off Leakage Current	$I_{S(off)}$	$V_S = \pm 14\text{ V}$ , $V_D = \mp 14\text{ V}$	Room Full	$\pm 0.01$	-1 -100	1 100	-5 -100	5 100	nA
Drain Off Leakage Current	$I_{D(off)}$		Room Full	$\pm 0.02$	-1 -100	1 100	-5 -100	5 100	
Drain On Leakage Current	$I_{D(on)}$	$V_S = V_D = \pm 14\text{ V}$	Room Full	$\pm 0.01$	-1 -200	1 200	-5 -200	5 200	
<b>Digital Control</b>									
Input Current	$I_{INL}$ , $I_{INH}$	$V_{IN} = 0\text{ V}$ or $= 2.4\text{ V}$	Room Full	-0.0004	-1 -10	1 10	-1 -10	1 10	$\mu\text{A}$
<b>Dynamic Characteristics</b>									
Turn-On Time	$t_{ON}$	See Figure 2	Room			550		550	ns
Turn-Off Time	$t_{OFF}$		Room			340		340	
Turn-On Time Write	$t_{ON, \overline{WR}}$	See Figure 3	Room			550		550	
Turn-Off Time Write	$t_{OFF, \overline{WR}}$		Room			340		340	
Write Pulse Width	$t_W$	See Figure 4	Room	120	150		150		
Input Setup Time	$t_S$		Room	130	180		180		
Input Hold Time	$t_H$		Full	0	20		20		
Charge Injection	Q	$C_L = 1000\text{ pF}$ $V_{GEN} = 0\text{ V}$ , $R_{GEN} = 0\ \Omega$	Room	20					pC
Source-Off Capacitance	$C_{S(off)}$	$f = 1\text{ MHz}$ , $V_S$ , $V_D = 0\text{ V}$	Room	8					pF
Drain-Off Capacitance	$C_{D(off)}$		Room	9					
Channel-On Capacitance	$C_{D(on)}$		Room	29					
Off Isolation	OIRR	$V_S = 1\text{ V}_{p-p}$ , $f = 100\text{ kHz}$ $C_L = 15\text{ pF}$ , $R_L = 1\text{ k}\Omega$	Room	70					dB
Interchannel Crosstalk	$X_{TALK}$		Room	90					
<b>Power Supplies</b>									
Positive Supply Current	I+	All Channels On or Off $V_{IN} = 0\text{ V}$ or $2.4\text{ V}$	Full	0.8		1.5		1.5	mA
Negative Supply Current	I-		Room	-0.4	-1		-1		

Notes:

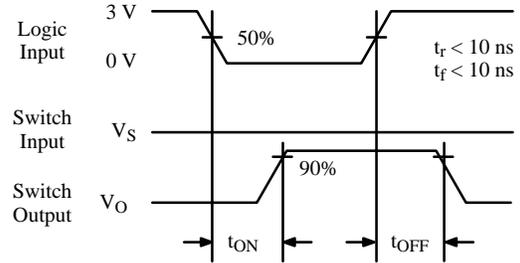
- Refer to PROCESS OPTION FLOWCHART.
- Room = 25°C, Full = as determined by the operating temperature suffix.
- Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- Guaranteed by design, not subject to production test.
- $V_{IN}$  = input voltage to perform proper function.

## Test Circuits

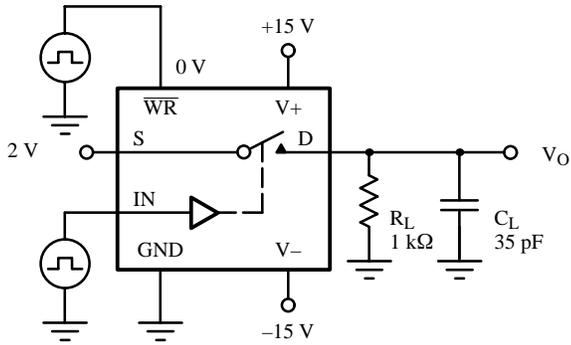


$C_L$  (includes fixture and stray capacitance)

$$V_O = V_S \frac{R_L}{R_L + r_{DS(on)}}$$

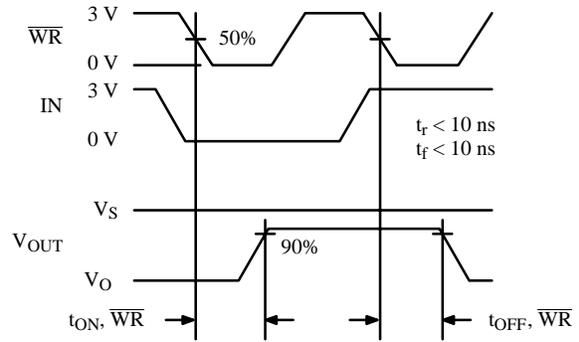


**Figure 2.** Switching Time

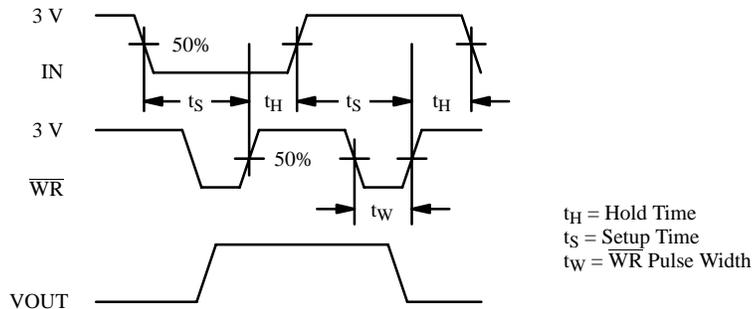


$C_L$  (includes fixture and stray capacitance)

$$V_O = V_S \frac{R_L}{R_L + r_{DS(on)}}$$



**Figure 3.**  $\overline{WR}$  Switching Time



The latches are level sensitive. When  $\overline{WR}$  is held low the latches are transparent and the switches respond to the digital inputs. The digital inputs are latched on the rising edge of  $\overline{WR}$ .

**Figure 4.**  $\overline{WR}$  Setup Conditions

## Test Circuits (Cont'd)

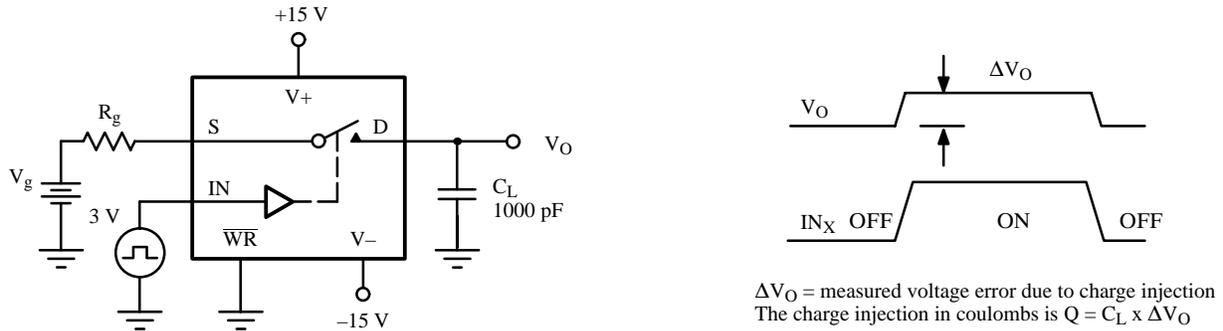
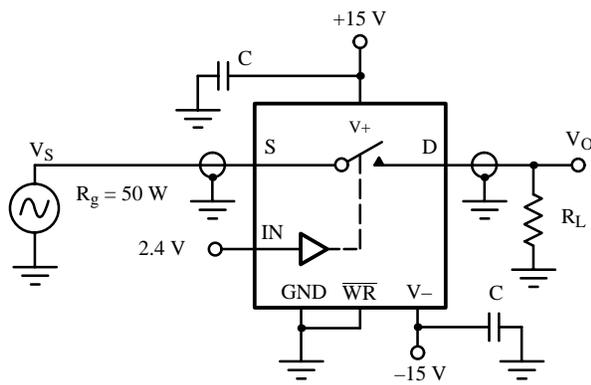


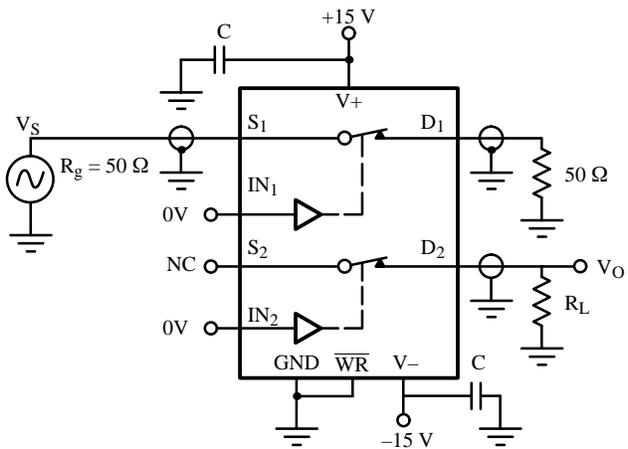
Figure 5. Charge Injection



$$\text{Off Isolation} = 20 \log \left| \frac{V_S}{V_O} \right|$$

C = RF bypass

Figure 6. Off Isolation



$$X_{\text{TALK}} \text{ Isolation} = 20 \log \left| \frac{V_S}{V_O} \right|$$

C = RF bypass

Figure 7. Channel-to-Channel Crosstalk

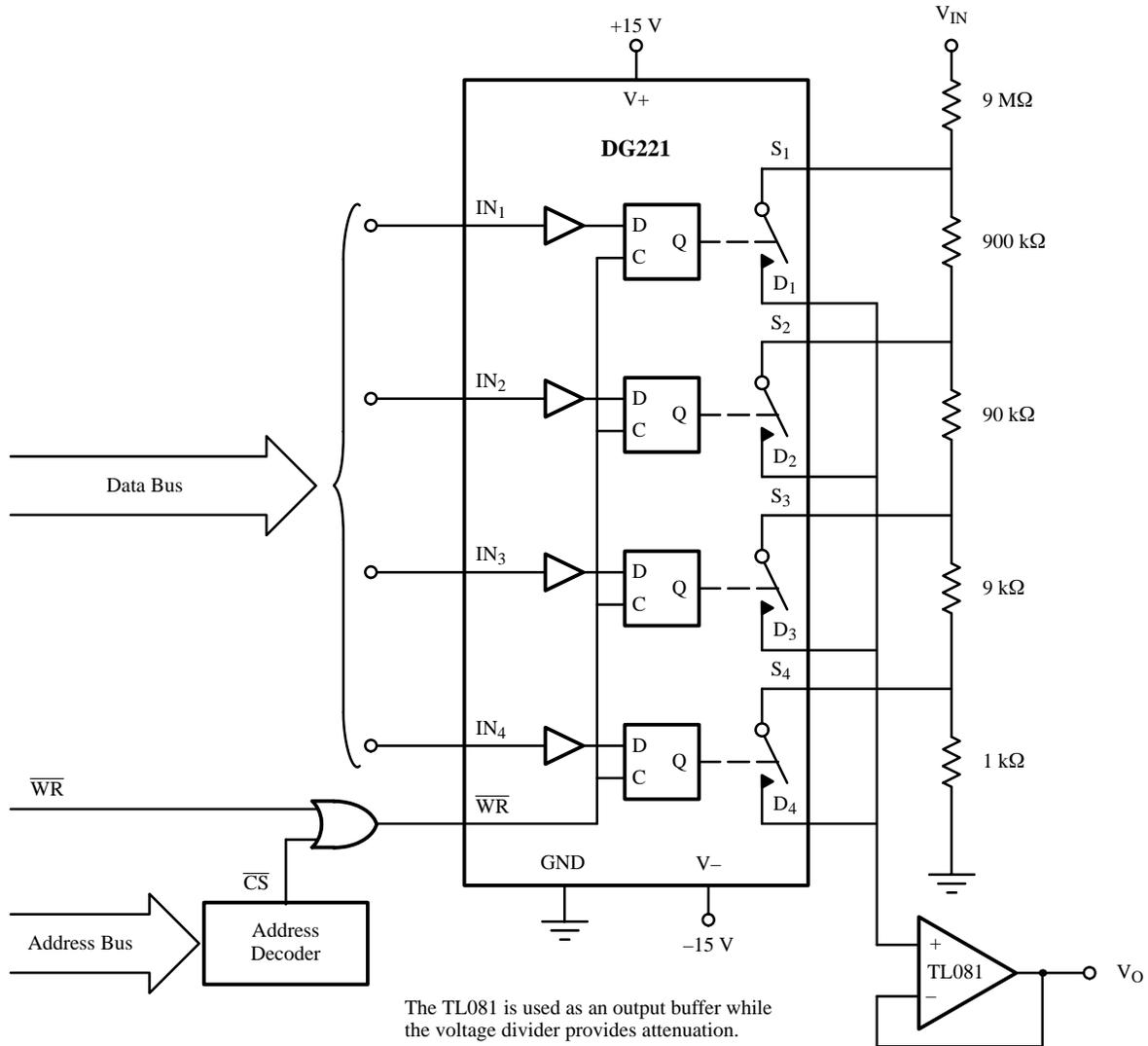
## Application Hints<sup>a</sup>

V+ Positive Supply Voltage (V)	V- Negative Supply Voltage (V)	GND (V)	WR (V)	V <sub>IN</sub> Logic Input Voltage V <sub>INH(min)</sub> /V <sub>INL(max)</sub> (V)	V <sub>S</sub> or V <sub>D</sub> Analog Voltage Range (V)
15	-15	0	2.4/0.8	2.4/0.8	-15 to 15
20	-20	0	2.4/0.8	2.4/0.8	-20 to 20
10	-10	0	2.4/0.8	2.4/0.8	-10 to 10
10	-5	0	2.4/0.8	2.4/0.8	-5 to 10

Notes:

a. Application Hints are for DESIGN AID ONLY, not guaranteed and not subject to production testing.

## Applications



**Figure 8.**  $\mu$ P-Controlled Analog Signal Attenuator

**Truth Table**

IN <sub>1</sub>	IN <sub>2</sub>	IN <sub>3</sub>	IN <sub>4</sub>	$\overline{\text{WR}}^a$	On Switch
0	0	0	0	0	All
1	1	1	1	0	None
0	1	1	1	0	1
1	0	1	1	0	2
1	1	0	1	0	3
1	1	1	0	0	4

**Output Attenuation for Figure 8**

WR	IN <sub>1</sub>	IN <sub>2</sub>	IN <sub>3</sub>	IN <sub>4</sub>	Gain
0	0	1	1	1	0.1
0	1	0	1	1	0.01
0	1	1	0	1	0.001
0	1	1	1	0	0.0001

Notes:

- a.  $\overline{\text{WR}}$  may be held at "0" for temporary operation similar to DG201A/DG201B. With  $\overline{\text{WR}}$  at "0" SW<sub>1</sub> will remain on as long as IN<sub>1</sub> is held at "0".